

RGW80TK65

650V 40A Field Stop Trench IGBT

V _{CES}	650V
I _{C (100°C)}	23A
V _{CE(sat) (Typ.)}	1.5V@I _C =40A
P_D	81W

Features

- 1) Low Collector Emitter Saturation Voltage
- 2) High Speed Switching
- 3) Low Switching Loss & Soft Switching
- 4) Pb free Lead Plating; RoHS Compliant

Applications

PFC

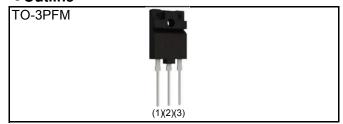
UPS

Welding

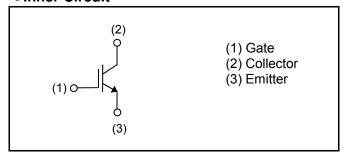
Solar Inverter

ΙH

Outline



●Inner Circuit



Packaging Specifications

	Packaging	Tube
	Reel Size (mm)	-
Typo	Tape Width (mm)	-
Type	Basic Ordering Unit (pcs)	450
	Packing Code	C11
	Marking	RGW80TK65

● Absolute Maximum Ratings (at T_C = 25°C unless otherwise specified)

Parameter		Symbol	Symbol Value	
Collector - Emitter Voltage		V_{CES}	650	V
Gate - Emitter Voltage		V_{GES}	±30	V
Collector Current	T _C = 25°C	I _C	39	А
	T _C = 100°C	l _C 23		А
Pulsed Collector Current		I _{CP} *1	160	А
Power Dissipation	T _C = 25°C	P _D	81	W
	T _C = 100°C	P _D	40	W
Operating Junction Temperature		T _j	-40 to +175	°C
Storage Temperature		T _{stg}	-55 to +175	°C

^{*1} Pulse width limited by T_{imax}.

●Thermal Resistance

Parameter	Symbol	Values			Unit
raiametei		Min.	Тур.	Max.	Offic
Thermal Resistance IGBT Junction - Case	$R_{\theta(j-c)}$	1	-	1.85	°C/W

●IGBT Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit	
r ai ai nietei	Syllibol	Conditions		Тур.	Max.	OTIIL	
Collector - Emitter Breakdown Voltage	BV _{CES}	$I_C = 10 \mu A, V_{GE} = 0 V$	650	1	-	V	
Collector Cut - off Current	I _{CES}	V _{CE} = 650V, V _{GE} = 0V	1	1	10	μΑ	
Gate - Emitter Leakage Current	I _{GES}	$V_{GE} = \pm 30V, V_{CE} = 0V$	-	-	±200	nA	
Gate - Emitter Threshold Voltage	$V_{\text{GE(th)}}$	$V_{CE} = 5V, I_{C} = 26.0 \text{mA}$	5.0	6.0	7.0	V	
Collector - Emitter Saturation Voltage	V _{CE(sat)}	$I_C = 40A, V_{GE} = 15V$ $T_j = 25^{\circ}C$ $T_j = 175^{\circ}C$	-	1.5 1.85	1.9 -	V	

●IGBT Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Darameter	Symbol	Conditions	Values			Unit
Parameter	Symbol Conditions		Min.	Тур.	Max.	Uffil
Input Capacitance	C _{ies}	V _{CE} = 30V	-	3320	-	
Output Capacitance	C _{oes}	V _{GE} = 0V	-	83	-	pF
Reverse Transfer Capacitance	C _{res}	f = 1MHz	-	60	-	
Total Gate Charge	Q_g	V _{CE} = 400V	-	110	-	
Gate - Emitter Charge	Q_{ge}	I _C = 40A	-	23	-	nC
Gate - Collector Charge	Q_{gc}	V _{GE} = 15V	-	41	-	
Turn - on Delay Time	t _{d(on)}	I _C = 40A, V _{CC} = 400V	-	44	-	
Rise Time	t _r	$V_{GE} = 15V, R_G = 10\Omega$	-	17	-	
Turn - off Delay Time	t _{d(off)}	T _j = 25°C	-	143	-	ns
Fall Time	t _f	Inductive Load	-	34	-	
Turn - on Switching Loss	E _{on}	*E _{on} includes diode	-	0.76	-	
Turn - off Switching Loss	E _{off}	reverse recovery	-	0.72	-	mJ
Turn - on Delay Time	t _{d(on)}	I _C = 40A, V _{CC} = 400V	-	41	-	
Rise Time	t _r	$V_{GE} = 15V, R_{G} = 10\Omega$	-	18	-	
Turn - off Delay Time	t _{d(off)}	T _j = 175°C	-	158	-	ns
Fall Time	t _f	Inductive Load	-	74	-	
Turn - on Switching Loss	E _{on}	*E _{on} includes diode	-	0.76	-	m l
Turn - off Switching Loss	E _{off}	reverse recovery	-	0.91	-	mJ
		I _C = 160A, V _{CC} = 520V				
Reverse Bias Safe Operating Area	RBSOA	V _P = 650V, V _{GE} = 15V	FU	LL SQUA	RE	-
		$R_G = 100\Omega, T_j = 175^{\circ}C$				

Fig.1 Power Dissipation vs. Case Temperature

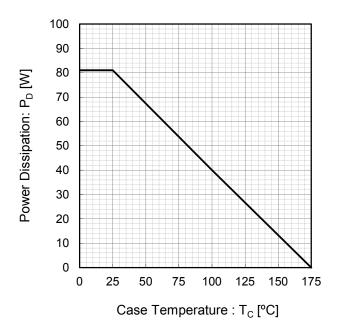


Fig.2 Collector Current vs. Case Temperature

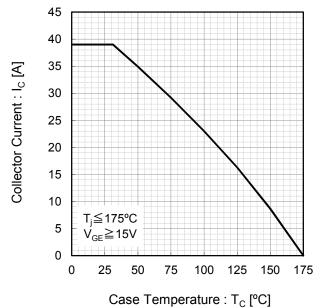


Fig.3 Forward Bias Safe Operating Area

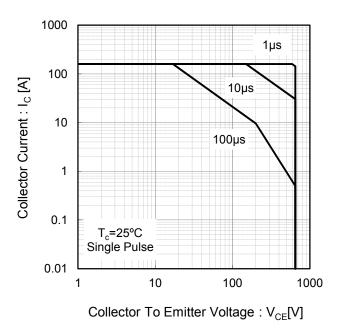


Fig.4 Reverse Bias Safe Operating Area

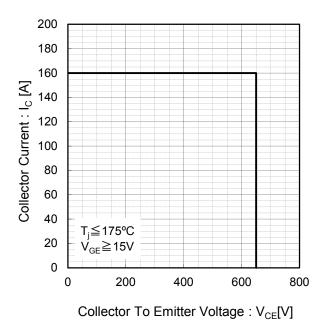


Fig.5 Typical Output Characteristics

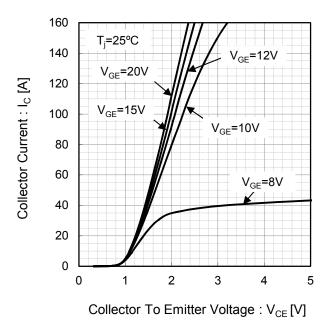
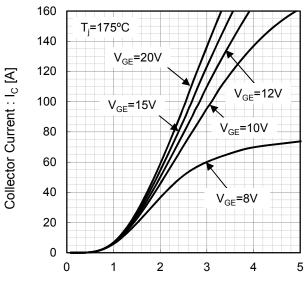


Fig.6 Typical Output Characteristics



Collector To Emitter Voltage : $V_{CE}[V]$

Fig.7 Typical Transfer Characteristics

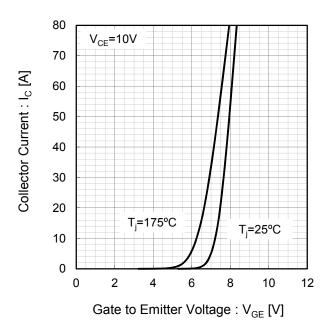


Fig.8 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature

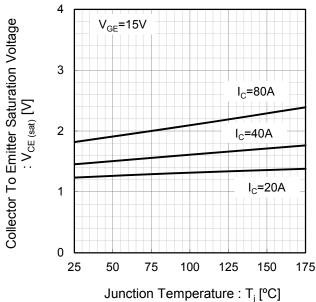
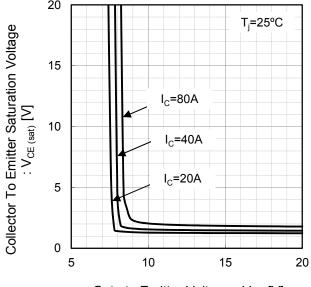
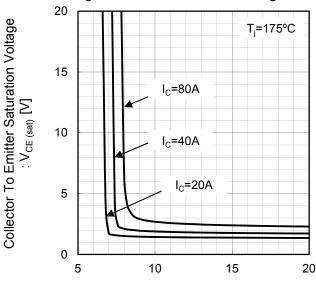


Fig.9 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage



Gate to Emitter Voltage : $V_{GE}[V]$

Fig.10 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage



Gate to Emitter Voltage : V_{GE} [V]

Fig.11 Typical Switching Time vs. Collector Current

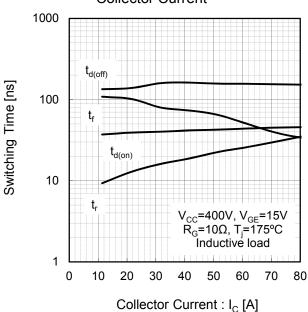


Fig.12 Typical Switching Time vs. Gate Resistance

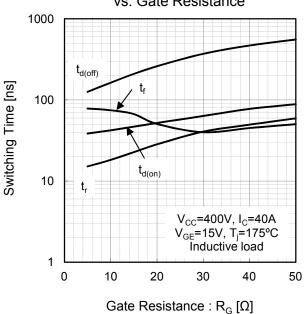


Fig.13 Typical Switching Energy Losses vs. Collector Current 10 Switching Energy Losses [mJ] 1 E_{off} E_{on} 0.1 V_{CC} =400V, V_{GE} =15V R_{G} =10 Ω , T_{j} =175°C Inductive load 0.01 0 10 20 30 40 50 60 70 80 Collector Current : I_C [A]

Gate Resistance 10 Switching Energy Losses [mJ] E_{off} 1 E_{on} 0.1 V_{CC}=400V, I_C=40A V_{GE}=15V, T_j=175°C Inductive load 0.01 10 0 20 30 40 50

Gate Resistance : $R_G [\Omega]$

Fig.14 Typical Switching Energy Losses vs.

Fig.15 Typical Capacitance vs.
Collector To Emitter Voltage 10000 Cies 1000 Capacitance [pF] Coes 100 Cres 10 f=1MHz V_{GE}=0V =25°C 0.01 0.1 1 10 100 Collector To Emitter Voltage : $V_{CE}[V]$

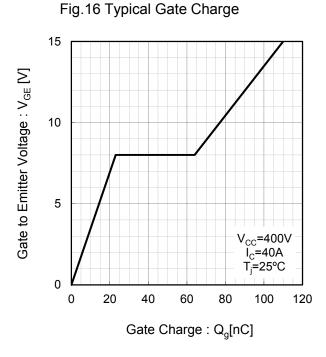
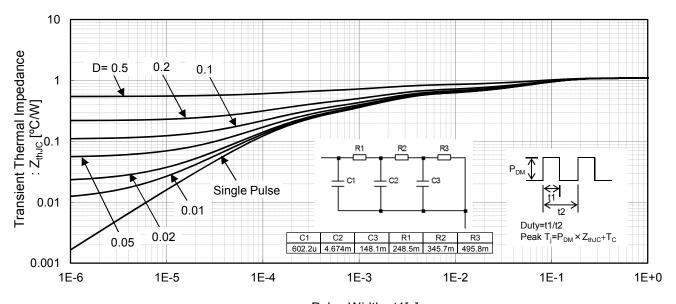


Fig.17 Typical IGBT Transient Thermal Impedance



Pulse Width: t1[s]

•Inductive Load Switching Circuit and Waveform

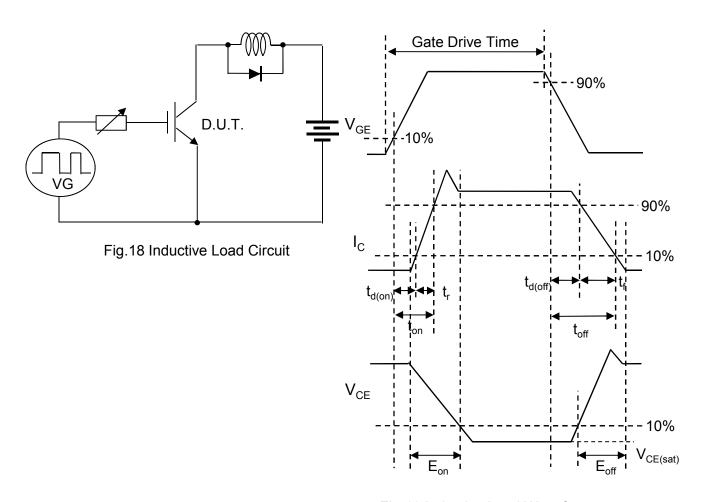


Fig.19 Inductive Load Waveform

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